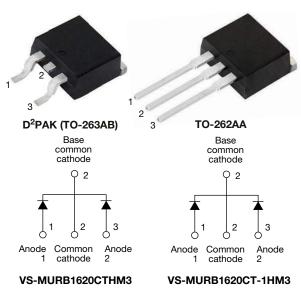
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# VS-MURB1620CTHM3, VS-MURB1620CT-1HM3

**Vishay Semiconductors** 

# Ultrafast Rectifier, 2 x 8 A FRED Pt®



## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	2 x 8 A						
V <sub>R</sub>	200 V						
V <sub>F</sub> at I <sub>F</sub>	0.895 V						
t <sub>rr</sub> (typ)	19 ns						
T <sub>J</sub> max.	175 °C						
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA						
Circuit configuration	Common cathode						

### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **DESCRIPTION / APPLICATIONS**

MUR.. series are the state of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

## **MECHANICAL DATA**

**Case:** D<sup>2</sup>PAK (TO-263AB), TO-262AA

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V	
Average rectified forward current	per leg	1		8.0		
Average rectilied forward current	total device	I <sub>F(AV)</sub>	Rated V <sub>R</sub> , T <sub>C</sub> = 150 °C	16	^	
Non-repetitive peak surge current per leg		I <sub>FSM</sub>		100	A	
Peak repetitive forward current per	leg	I <sub>FM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 150 °C	16		
Operating junction and storage tem	peratures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-		
Forward valtage	V	I <sub>F</sub> = 8 A	-	-	0.975	V	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A, T <sub>J</sub> = 150 °C	-	-	0.895		
Reverse leakage current	I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	-	5		
neverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	250	- μΑ	
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	25	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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COMPLIANT HALOGEN

FREE



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \ ^{\circ}C$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS M				UNITS	
Reverse recovery time		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 10$	0 A/µs, V <sub>R</sub> = 30 V	-	19	-		
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	20	-	ns A nC	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 160 V	-	34	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.7	-		
Feak recovery current		T <sub>J</sub> = 125 °C		-	4.2	-		
	0	T <sub>J</sub> = 25 °C		-	23	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	75	-	no	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	3.0			
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>		-	-	50	°C/W		
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	2.0	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking davias		Case style D <sup>2</sup> PAK (TO-263AB)		MURB1	620CTH			
Marking device		Case style TO-262AA		MURB16	20CT-1H			

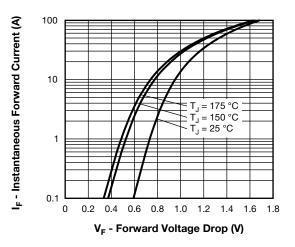


Fig. 1 - Typical Forward Voltage Drop Characteristics

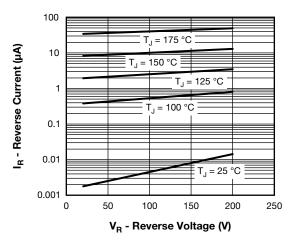


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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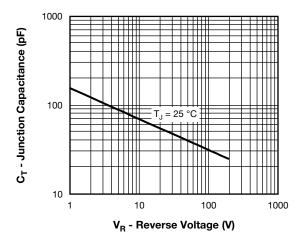


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

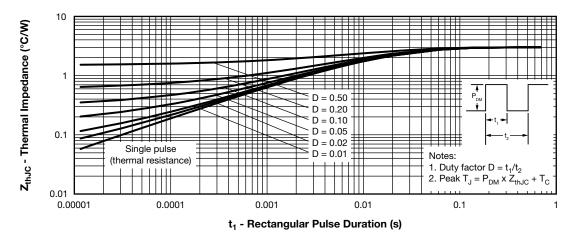
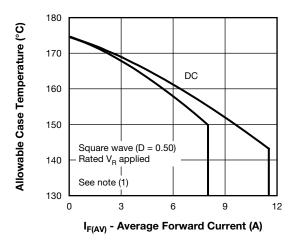
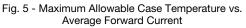


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_{R} (1 - D); I_{R} \text{ at } V_{R1} = \text{rated } V_{R} \end{array}$ 

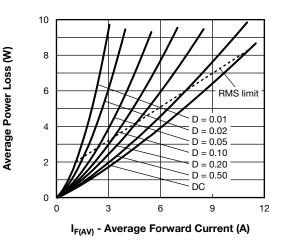


Fig. 6 - Forward Power Loss Characteristics

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VS-MURB1620CTHM3, VS-MURB1620CT-1HM3 ISHAY www.vishay.com **Vishay Semiconductors** 60 200 V<sub>R</sub> = 160 V V<sub>R</sub> = 160 V T<sub>J</sub> = 125 °C T<sub>1</sub> = 125 °C  $I_{\rm F} = 30 \, {\rm A}$ = 25 °C T<sub>J</sub> = 25 °C 50 160  $I_{F} = 15 \text{ A}$  $I_{c} = 8 A$ I<sub>F</sub> = 30 A  $I_{F} = 15 A$ 1 40 120 Q<sub>rr</sub> (nC) I<sub>F</sub> = 8 A t<sub>rr</sub> (ns) Ξ 30 80 20 40 10 0 100 1000 100 1000 dl<sub>F</sub>/dt (A/µs) dl<sub>F</sub>/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt



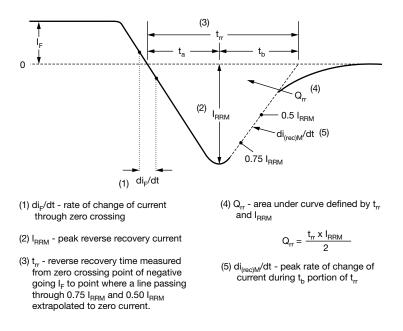


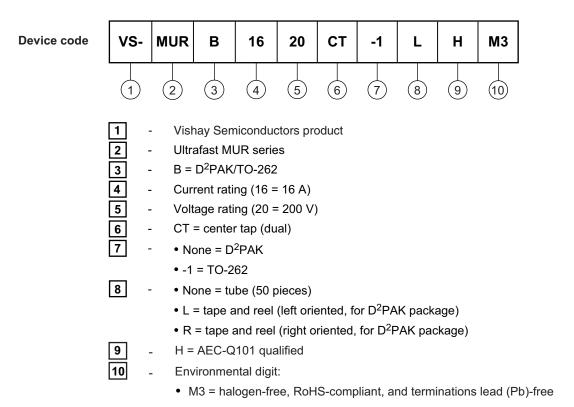
Fig. 9 - Reverse Recovery Waveform and Definitions

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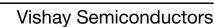
### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-MURB1620CTHM3	50	Antistatic plastic tube				
VS-MURB1620CT-1HM3	50	Antistatic plastic tube				
VS-MURB1620CTLHM3	800	13" diameter reel				
VS-MURB1620CTRHM3	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95046				
Dimensions	TO-262AA	www.vishay.com/doc?95419				
Part marking information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95444				
	TO-262AA	www.vishay.com/doc?95443				
Packaging information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95032				
SPICE model		www.vishay.com/doc?96995				

# **Outline Dimensions**

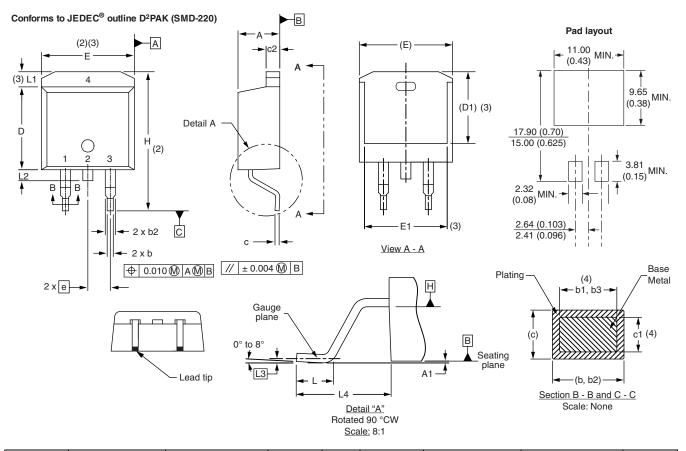


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D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches

SHA



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	INCHES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	) BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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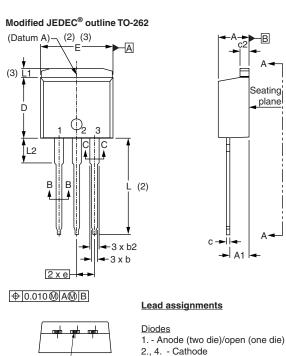
## **Outline Dimensions**



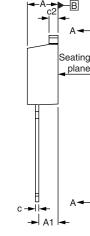
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**TO-262** 

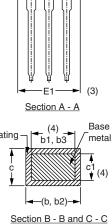
### **DIMENSIONS** in millimeters and inches



Lead tip -



E1 Plating



Е

D1(3)

Scale: None

SYMBOL	MILLIM	ETERS	INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.36	3.71	0.132	0.146		

3. - Anode

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches (6)

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body <sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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